IFW B/92

Docket No.: 57454-970

**PATENT** 

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

/In re Application of

Customer Number: 20277

Hideto HIDAKA

Confirmation Number: 7630

Serial No.: 10/644,750

Group Art Unit: 2818 Allowed: May 24, 2004

Filed: August 21, 2003

Examiner: Yoha, Connie C.

For: MIS SEMICONDUCTOR DEVICE HAVING IMPROVED GATE INSULATING FILM

RELIABILITY

## REQUEST FOR ACKNOWLEDGEMENT OF THE "CORRECTED" CITED ART

Mail Stop ISSUE FEE Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

We are in receipt of the Notice of Allowance dated May 24, 2004.

It is noted that the Examiner has not initialed a copy of the corrected PTO-1449 that accompanied the Supplemental Information Disclosure Statement filed March 17, 2004. The Examiner initialed and returned PTO-1449, filed August 21, 2003, which contained an inverted reference number. The Supplemental IDS filed March 17, 2004 corrected this typographical error. A copy of the corrected 1449 is attached and for the Examiner's convenience, the corrected reference is highlighted. It is respectfully requested that the Examiner initial the pto-1449 and provide applicants with an initialed copy thereof.

It is respectfully requested that the records of the Patent Office be corrected to ensure that the deed of Letters Patent will be printed correctly.

Respectfully submitted,

MCDERMOTT WILL & EMERY LLP

Stephen A. Becker Registration No. 26,527

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Date: June 9, 2004

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INFORMATION DISCLOSURE CITATION IN AN APPLICATION					ATTY. DOCKET NO. <b>57454-970</b>		SERIAL NO. No. 10/644,750				
						APPLICANT Hideto HIDAKA					
(PTO-1449)					FILING DATE GROUP August 21, 2003 2818						
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EXAMINER'S INITIALS	CITE NO.	Num	Document Number ber-Kind Codez (# known)	Publication Da MM-DD-YYY		Name of Patentee or Appli Document			Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
		US	6,414,889	07/2002		Chen et al.					
		US	6,107,134	08/2000		Lu et al.					
		US	5,956,279	09/1999		Mo et al.					
		US	5,694,364	12/1997		Morishita et al.					
		US	5,379,260	01/1995	<b>→</b>	McClure					
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EXAMINER'S INITIALS	CITE NO.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.   "A Precise On-Chip Voltage Generator for a Gigascale DRAM with a Negative Word-Line Scheme", by Tanaka et al., IEEE Journal of Solid-State Circuits, Vol. 34, No. 8, 8/1999, pp. 1084-1090.									
	"Ultra LSI Memory" by Kiyoo Ito, Advanced Electronics Series, November 5, 1994, published by Baifukan, pp. 351-371.										
"An Experimental 256-Mb DRAM with Boosted Sense-Ground Scheme", by Asakura et al., IEEE Journal of Solid-State Circuits, Vol. 29, No. 11, 11/1994, pp. 1303-1309.											
EXAMINER .						DATE CONSIDERED					

\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

1 Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.